

Sz. Kolozsvári^{a)}, P. Pesch^{a)}, C. Ziebert^{b)}, S. Ulrich^{b)}

a) TZO – Technologiezentrum für Oberflächentechnik Rheinbreitbach GmbH, Maarweg 30, 53619 Rheinbreitbach, Germany

b) Forschungszentrum Karlsruhe, Institut für Materialforschung I, Hermann-von-Helmholtz-Platz 1, 76344 Eggenstein-Leopoldshafen, Germany

* Corresponding author, Tel.: +49 (0)2224 94 21 13; Fax: +49 (0)2224 94 21 20, E-mail adress: kolozsvari@tzo-gmbh.de

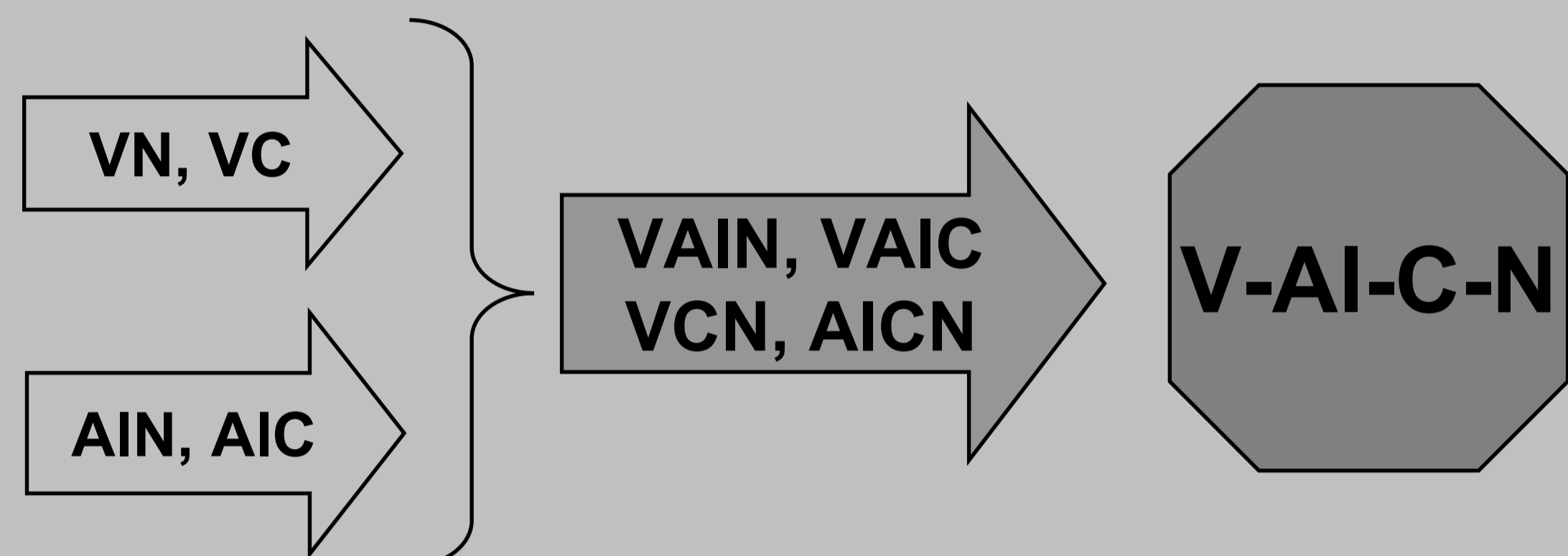
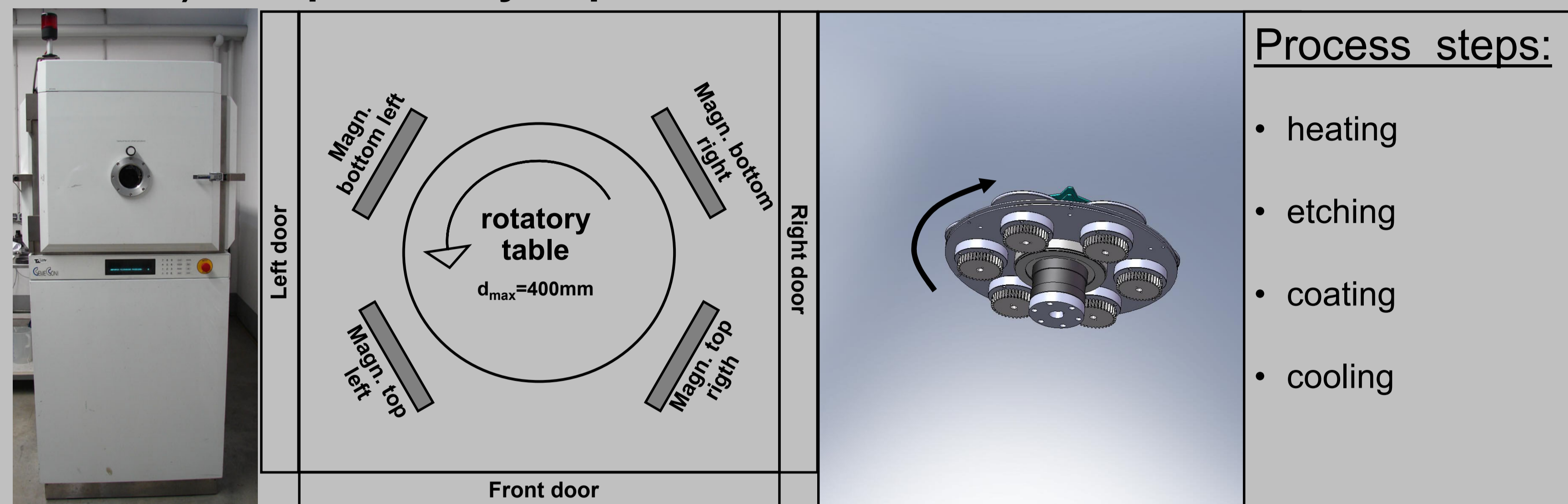
Deposition and characterization of hard coatings in the material system V-Al-N by reactive magnetron-sputtering

Aim of the work: deposition of **new coatings** in the material system **V-Al-N** on **industrial plants**, to achieve metastable nanostructured hard layers through systematical variation of deposition parameters as power density, plasma pressure and variation of the partial pressure of process-gases (Ar:N₂)

General approach:

- binary coatings: **VN**, **VC** (planned), **AIN**, (**AIC**)
- ternary coatings **VAIN**, **VCN**, **VAIC**, **AICN**
- V-Al-C-N-coatings

Realisation: dc magnetron-sputter industrial deposition system (CemeCon CC800/8) with possibility to process in rf mode



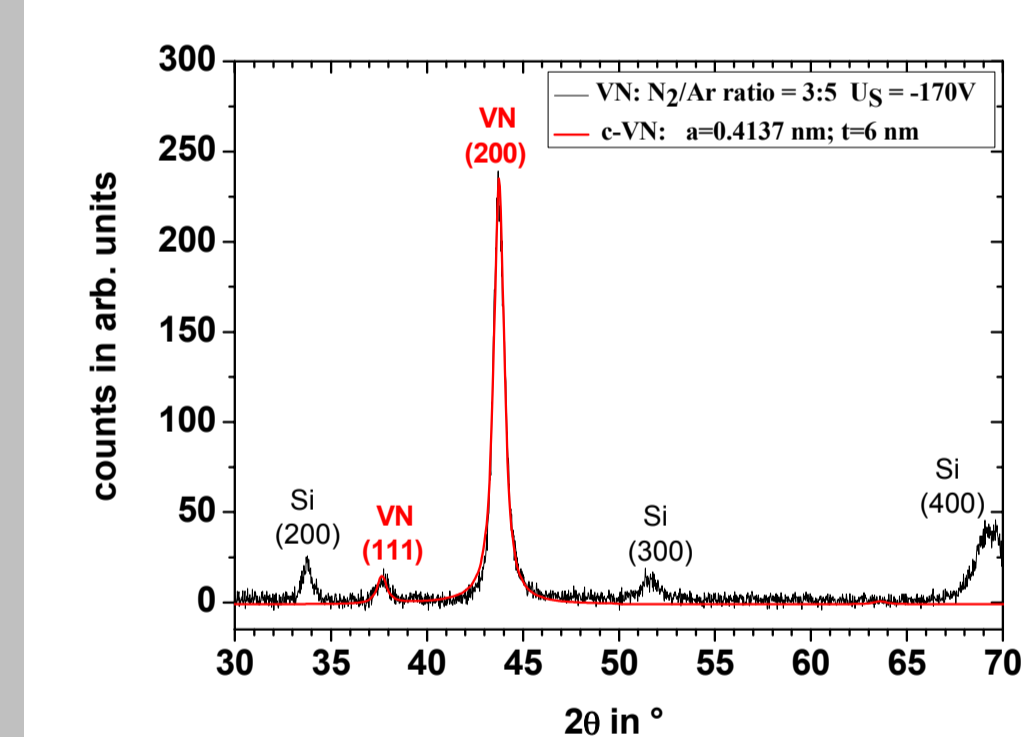
Flexible controlling: variation of many parameters in each process step possible

First results in dc-magnetron-sputtered binary VN-, AIN- and VAIN-coatings:

VN-coatings:

Varied coating parameters Ar:N₂ ratio and U_{bias}

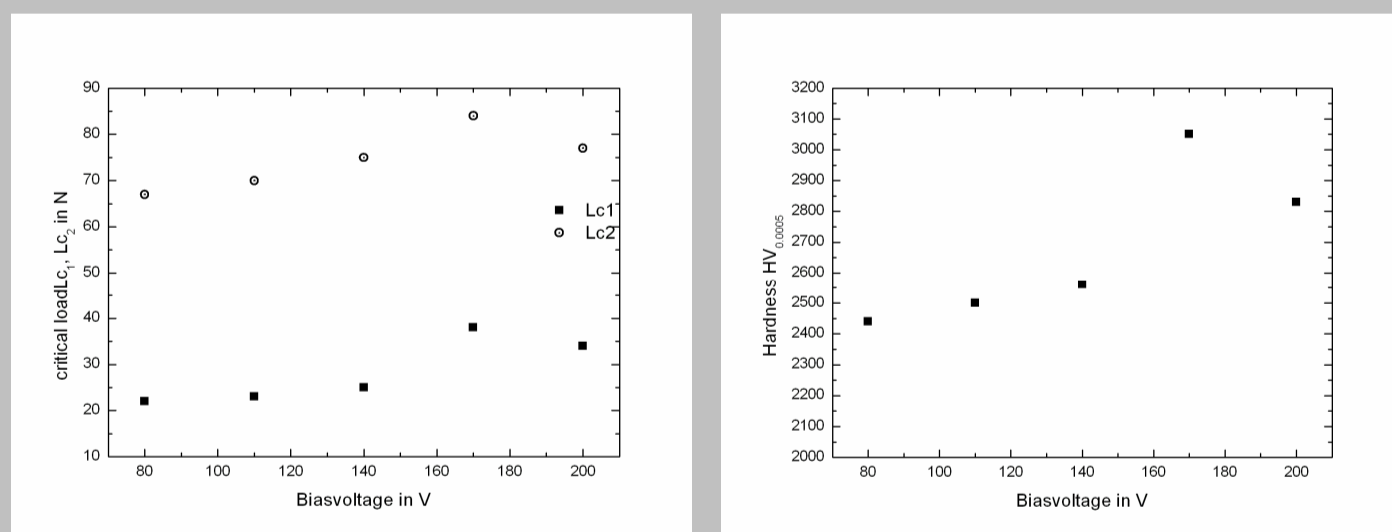
Ar:N ₂ -ratio	U _{bias} in V	L _{c1}	HV _{0.005}
250/150	-200	34	2830
250/150	-170	38	3050
250/150	-140	25	2560
250/150	-110	23	2500
250/150	-80	22	2440



XRD-spectra: nanocrystalline structure of layer with best mechanical properties

nc-VN	N in at%	V in at%
6nm	43,18	56,36

Composition measured by means of EPMA-method

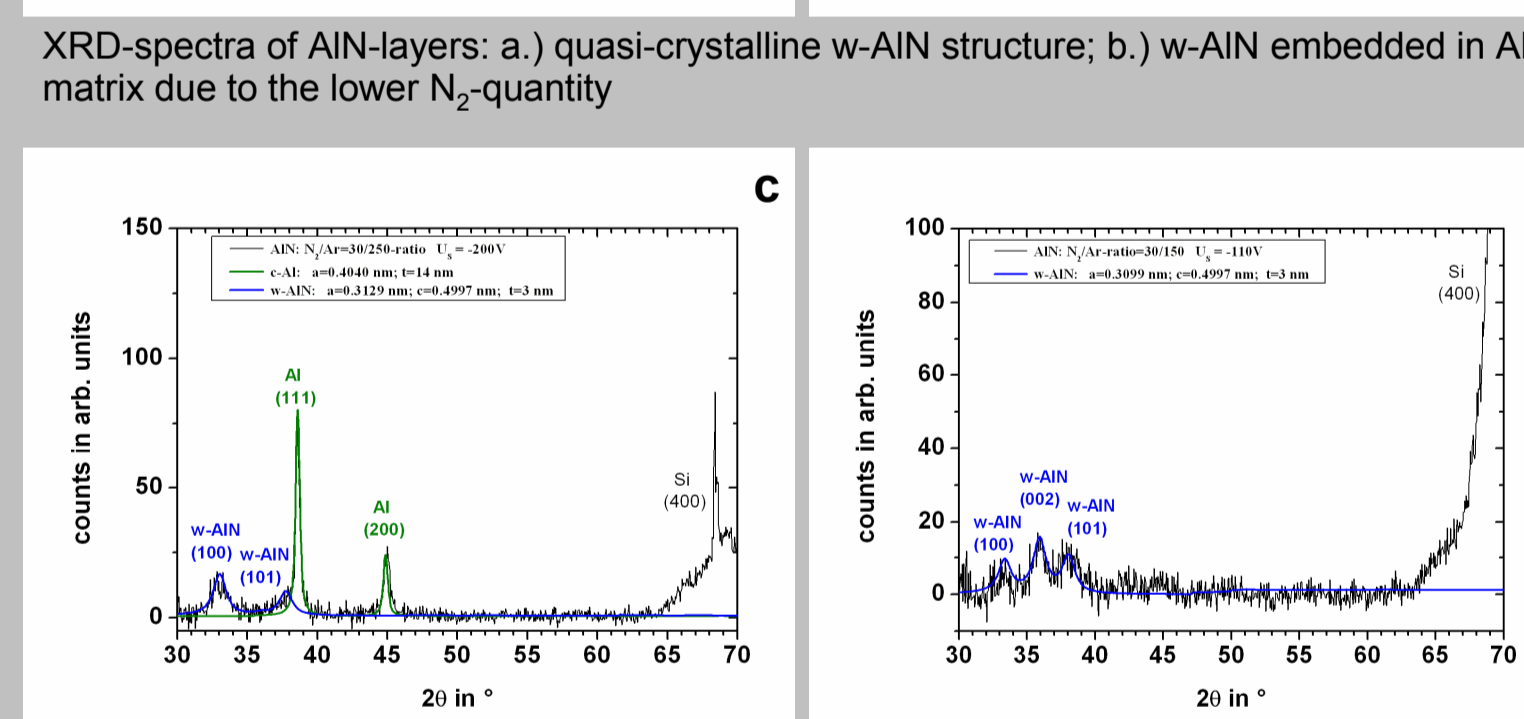
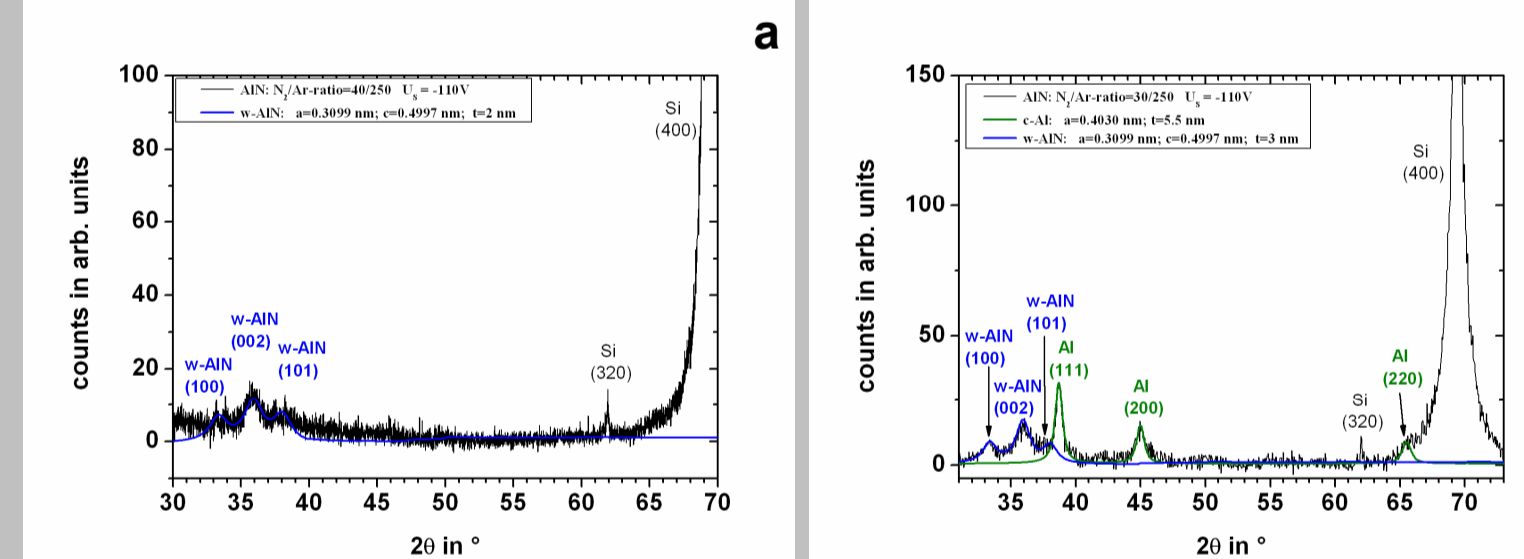


Dependence of critical load and hardness values on bias voltage

AIN-coatings:

Coating parameters (bias voltage variation)

AIN (or Al+N)	Ar:N ₂ -ratio	U _{bias} in V
2nm w-AIN	250/40	-110
3nm w-AIN+Al	250/30	-110
3nm w-AIN+Al	250/30	-200
3nm w-AIN	150/30	-110



AIN (or Al+N)	N in at%	Al in at%
2nm	38,07	60,68
3nm	30,08	68,78
3nm	43,54	55,37
3nm	17,07	75,22

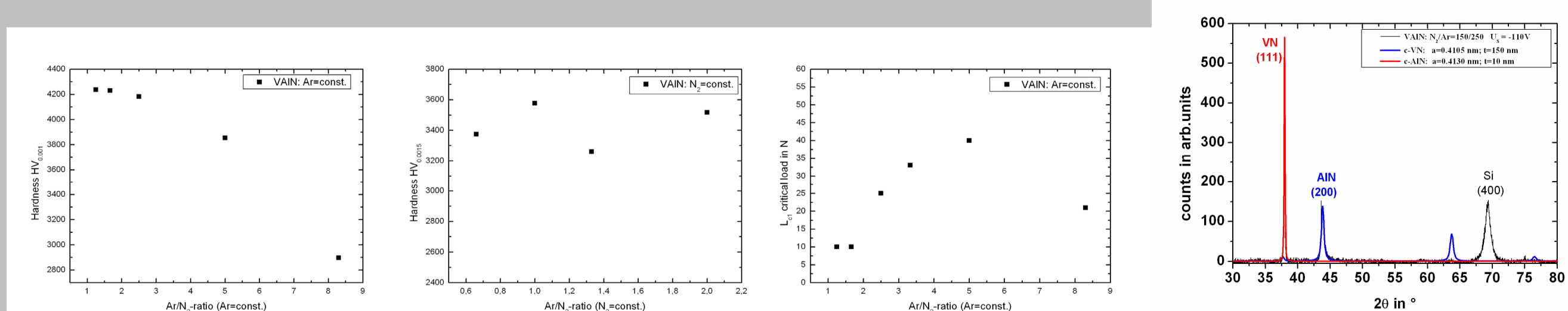
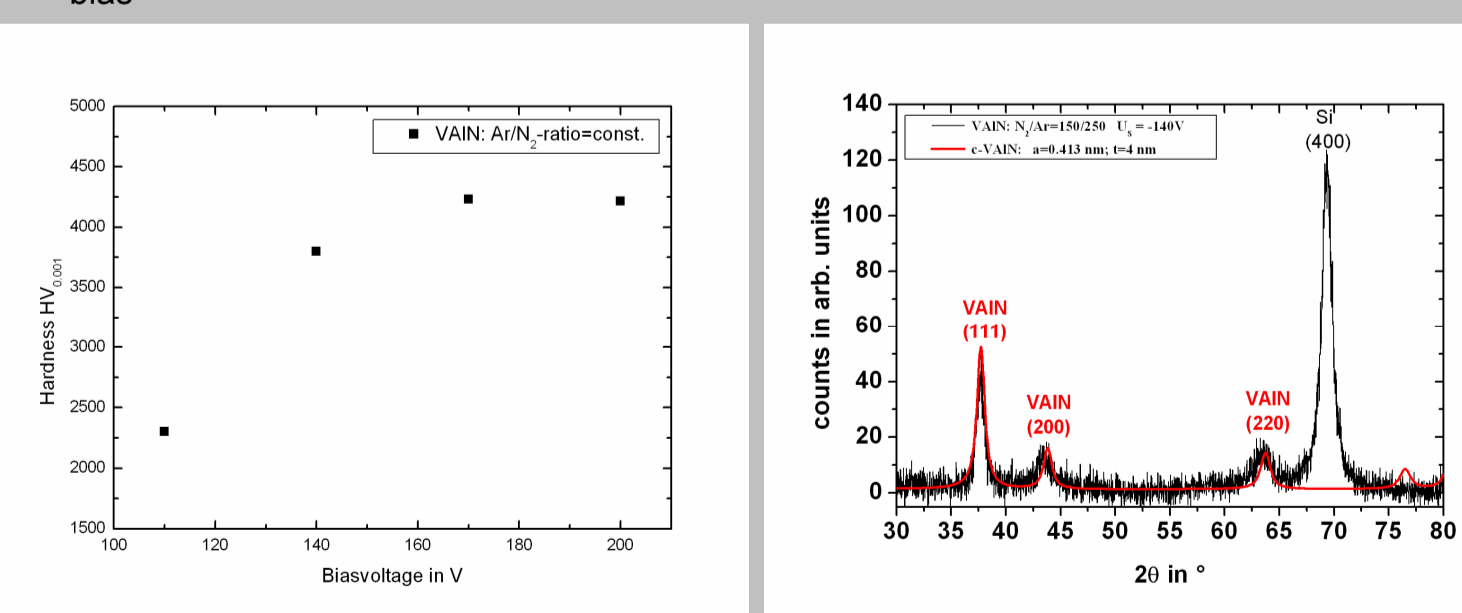
Composition measured by means of EPMA-method

XRD-spectra of AIN-layers: c.) w-AIN embedded in Al-matrix; d.) w-AIN structure

VAIN-coatings:

Varied coating parameters are pressure (Ar:N₂ ratio, 1.case Ar quantity=const., 2.case N₂=const.) and U_{bias}

Ar:N ₂ -ratio 1.case	Ar:N ₂ -ratio 2.case	U _{bias} in V at Ar:N ₂ =250/150
250/30	300/150	-80
250/50	250/150	-110
250/75	200/150	-140
250/100	150/150	-170
250/150	100/150	-200



Results and Outlook:

Results VN:

- VN-coating nanocrystalline
- average crystallite size ~6nm
- near-stoichiometric
- friction coefficient ~0.7

Results AIN:

- difficult processing by both dc and rf magnetron sputtering
- average crystallite size ~3nm
- w-AIN-structure, near-amorph
- friction coefficient ~0.7
- variation of Ar:N₂-ratio has no influence on friction coefficient

Results VAIN:

- VAIN-coating nanocrystalline
- average crystallite size ~4nm
- near-stoichiometric
- friction coefficient ~0.7
- probably mixture of VN and AIN
- mechanical properties advantageous

First experiments in the material system V-Al-C-N show:

- C-content in V-layers has an impact on friction coefficient (adjustable from 0.2-0.5)
- combination of hard, metastable materials with a low friction coefficient on an industrial machine feasible
- first steps to understand the quaternary V-Al-C-N system by studying binary VN-, AIN-, VC- and ternary VAIN-systems are done
- next steps: fabrication of VC-, VAIC- and AICN-layer-systems